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<b>0</b>	<b>For receiving Office use only</b>	
0-1	International Application No.	
0-2	International Filing Date	
0-3	Name of receiving Office and "PCT International Application"	
<b>0-4</b>	<b>Form - PCT/RO/101 PCT Request</b>	
0-4-1	Prepared Using	<b>PCT-SAFE Version 3.50 (Build 0002.162)</b>
0-5	<b>Petition</b>  The undersigned requests that the present international application be processed according to the Patent Cooperation Treaty	
0-6	Receiving Office (specified by the applicant)	<b>Korean Intellectual Property Office (RO/KR)</b>
0-7	Applicant's or agent's file reference	<b>SH-21483-PCT</b>
I	<b>Title of Invention</b>  <b>RECORDED MASTER FOR MANUFACTURING INFORMATION STORAGE MEDIUM AND METHOD OF MANUFACTURING THE MASTER</b>	
II	<b>Applicant</b>	
II-1	This person is:	
II-2	Applicant for	
II-4	Name:	
II-5	Address:  416, Maetan-dong, Yeongtong-gu Suwon-si Gyeonggi-do 442-742 Republic of Korea	
II-6	State of nationality	
II-7	State of residence	
II-8	Telephone No.	
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II-10	e-mail	
II-11	Applicant's registration No. with the Office	

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III-1	<b>Applicant and/or inventor</b>	
III-1-1	This person is:	applicant and inventor
III-1-2	Applicant for	US only
III-1-4	Name (LAST, First)	YOON, Du-Seop
III-1-5	Address:	315-601 Sibeomdanji Hanyang Apt., Seohyun-dong, Bundang-gu, Seongnam-si Gyeonggi-do463-776 Republic of Korea
III-1-6	State of nationality	KR
III-1-7	State of residence	KR
III-2	<b>Applicant and/or inventor</b>	
III-2-1	This person is:	applicant and inventor
III-2-2	Applicant for	US only
III-2-4	Name (LAST, First)	KIM, Joo-Ho
III-2-5	Address:	103-901 SK Apt., Seocheon-ri, Giheung-eup, Yongin-si Gyeonggi-do449-959 Republic of Korea
III-2-6	State of nationality	KR
III-2-7	State of residence	KR
III-3	<b>Applicant and/or inventor</b>	
III-3-1	This person is:	applicant and inventor
III-3-2	Applicant for	US only
III-3-4	Name (LAST, First)	PARK, In-Sik
III-3-5	Address:	615-801 Shinnamushil Kukdong Apt., 967-2 Yeongtong 2-dong, Yeongtong-gu, Suwon-si Gyeonggi-do443-733 Republic of Korea
III-3-6	State of nationality	KR
III-3-7	State of residence	KR
III-4	<b>Applicant and/or inventor</b>	
III-4-1	This person is:	applicant and inventor
III-4-2	Applicant for	US only
III-4-4	Name (LAST, First)	HWANG, In-Oh
III-4-5	Address:	325-801 Sibeomdanji Hanyang Apt., Seohyun-dong, Bundang-gu, Seongnam-si Gyeonggi-do463-776 Republic of Korea
III-4-6	State of nationality	KR
III-4-7	State of residence	KR

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III-5-1	This person is:	<b>applicant and inventor</b>
III-5-2	Applicant for	<b>US only</b>
III-5-4	Name (LAST, First)	<b>KIM, Hyun-Ki</b>
III-5-5	Address:	<b>216-702 Shinyoungtong Hyundai Apt., 868 Banwol-ri, Taeang-eup, Hwaseong-si Gyeonggi-do 445-983 Republic of Korea</b>
III-5-6	State of nationality	<b>KR</b>
III-5-7	State of residence	<b>KR</b>
IV-1	<b>Agent or common representative; or address for correspondence</b>  The person identified below is hereby/ has been appointed to act on behalf of the applicant(s) before the competent International Authorities as:	<b>agent</b>
IV-1-1	Name (LAST, First)	<b>LEE, Young-Pil</b>
IV-1-2	Address:	<b>The cheonghwa Building, 1571-18 Seocho-dong, Seocho-gu Seoul 137-874 Republic of Korea</b>
IV-1-3	Telephone No.	<b>82-2-588-8585</b>
IV-1-4	Facsimile No.	<b>82-2-588-8547</b>
IV-1-5	e-mail	<b>iplaw@yleepat.com</b>
IV-1-6	Agent's registration No.	<b>9-1998-000334-6</b>
V	<b>DESIGNATIONS</b>	
V-1	The filing of this request constitutes under Rule 4.9(a), the designation of all Contracting States bound by the PCT on the international filing date, for the grant of every kind of protection available and, where applicable, for the grant of both regional and national patents.	
V-2	Item V-2 may be used to exclude (irrevocably) the designations concerned in order to avoid the ceasing of the effect, under the national law, of an earlier national application from which priority is claimed. As to the consequences of such national law provisions in these and certain other States, see Designations in PCT-SAFE Help.	<b>KR</b>

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<b>VI-1</b>	<b>Priority claim of earlier national application</b>		
VI-1-1	Filing date	<b>06 September 2003 (06.09.2003)</b>	
VI-1-2	Number	<b>10-2003-0062421</b>	
VI-1-3	Country	<b>KR</b>	
<b>VI-2</b>	<b>Priority claim of earlier national application</b>		
VI-2-1	Filing date	<b>17 March 2004 (17.03.2004)</b>	
VI-2-2	Number	<b>10-2004-0018002</b>	
VI-2-3	Country	<b>KR</b>	
<b>VII-1</b>	<b>International Searching Authority Chosen</b>	<b>Korean Intellectual Property Office (ISA/KR)</b>	
<b>VIII</b>	<b>Declarations</b>	Number of declarations	
VIII-1	Declaration as to the identity of the inventor	-	
VIII-2	Declaration as to the applicant's entitlement, as at the international filing date, to apply for and be granted a patent	-	
VIII-3	Declaration as to the applicant's entitlement, as at the international filing date, to claim the priority of the earlier application	-	
VIII-4	Declaration of inventorship (only for the purposes of the designation of the United States of America)	-	
VIII-5	Declaration as to non-prejudicial disclosures or exceptions to lack of novelty	-	
<b>IX</b>	<b>Check list</b>	number of sheets	electronic file(s) attached
IX-1	Request (including declaration sheets)	<b>5</b>	✓
IX-2	Description	<b>11</b>	✓
IX-3	Claims	<b>3</b>	✓
IX-4	Abstract	<b>1</b>	✓
IX-5	Drawings	<b>8</b>	✓
IX-7	<b>TOTAL</b>	<b>28</b>	
	<b>Accompanying Items</b>	paper document(s) attached	electronic file(s) attached
IX-8	Fee calculation sheet	-	✓
IX-11	Copy of general power of attorney	-	<b>reference no.</b> <b>6-1-2004-0000213-65</b>
IX-17	PCT-SAFE physical media	-	-
IX-19	<b>Figure of the drawings which should accompany the abstract</b>	<b>4</b>	
IX-20	<b>Language of filing of the international application</b>	<b>English</b>	

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X-1	<b>Signature of applicant, agent or common representative</b>	<b>(PKCS7 Digital Signature)</b>
X-1-1	Name (LAST, First)	<b>LEE, Young-Pil</b>
X-1-2	Name of signatory	
X-1-3	Capacity	

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10-1	<b>Date of actual receipt of the purported international application</b>	
10-2	<b>Drawings:</b>	
10-2-1	Received	
10-2-2	Not received	
10-3	<b>Corrected date of actual receipt due to later but timely received papers or drawings completing the purported international application</b>	
10-4	<b>Date of timely receipt of the required corrections under PCT Article 11(2)</b>	
10-5	<b>International Searching Authority</b>	<b>ISA/KR</b>
10-6	<b>Transmittal of search copy delayed until search fee is paid</b>	

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11-1	<b>Date of receipt of the record copy by the International Bureau</b>	
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**PCT (ANNEX - FEE CALCULATION SHEET)**

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(This sheet is not part of and does not count as a sheet of the international application)

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0-1	International Application No.		
0-2	Date stamp of the receiving Office		
<b>0-4</b>	<b>Form PCT/RO/101 (Annex) PCT Fee Calculation Sheet</b>		
0-4-1	Prepared Using	<b>PCT-SAFE Version 3.50 (Build 0002.162)</b>	
<b>0-9</b>	<b>Applicant's or agent's file reference</b>	<b>SH-21483-PCT</b>	
<b>2</b>	<b>Applicant</b>	<b>SAMSUNG ELECTRONICS CO., LTD.</b>	
<b>12</b>	<b>Calculation of prescribed fees</b>	<b>fee amount/multiplier</b>	<b>Total amounts (KRW)</b>
12-1	Transmittal fee <b>T</b>	↔	<b>45000</b>
12-2-1	Search fee <b>S</b>	↔	<b>225000</b>
12-2-2	International search to be carried out by <b>KR</b>		
12-3	International filing fee (first 30 sheets) <b>i1</b>	<b>1329000</b>	
12-4	Remaining sheets <b>0</b>		
12-5	Additional amount <b>(X) 0</b>		
12-6	Total additional amount <b>i2</b>	<b>0</b>	
12-7	<b>i1 + i2 = i</b>	<b>1329000</b>	
12-12	Electronic Filing reduction (Full) <b>R</b>	<b>-285000</b>	
12-13	Total International filing fee (i-R) <b>I</b>	↔	<b>1044000</b>
12-14	Fee for priority document Number of priority documents requested <b>0</b>		
12-15	Fee per document <b>(X) 0</b>		
12-16	Total priority document fee: <b>P</b>	↔	
<b>12-17</b>	<b>TOTAL FEES PAYABLE (T+S+I+P)</b>	↔	<b>1314000</b>
<b>12-19</b>	<b>Mode of payment</b>	<b>cash</b>	

## Description

# RECORDED MASTER FOR MANUFACTURING INFORMATION STORAGE MEDIUM AND METHOD OF MANUFACTURING THE MASTER

### Technical Field

- [1] The present invention relates to a recorded master for manufacturing an information storage medium and a method of manufacturing the master, and more particularly, to a recorded master for manufacturing an information storage medium in which a pit or groove of a very small size can be formed by chemical and physical reactions between thin films and a stamper can be easily separated by a separation layer, and a method of manufacturing the master.

### Background Art

- [2] Generally, an information storage medium is widely employed as an information recording medium in an optical pickup apparatus for recording and/or reproducing information contactlessly. Optical discs as information storage media, are divided into a compact disc (CD), and a digital versatile disc (DVD) according to the information recording capacity. Optical discs capable of recording, deleting and reproducing information include a 650MB CD-R, CD-RW, 4.7GB DVD+RW, and so on. Furthermore, an HD-DVD with a recording capacity of 20GB or over is also under development.
- [3] Thus, the information storage media are being developed in the direction of increasing a recording capacity. Representative methods to increase a recording capacity include shortening the wavelength of a recording light source and heightening the numerical aperture of an object lens. Also, there is a method of constructing a recording layer as multiple layers.
- [4] Meanwhile, a pit or groove is formed on a substrate in any type of information storage media. As another method of increasing a recording capacity, the pit size or track pitch of a groove can be reduced.
- [5] Capacities of information storage media, pit sizes, and track pitches by generation are shown in the following Table 1:
- [6] Table 1
- [7]

	1st generation	2nd generation	3rd generation
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Spec name	CD	DVD	BD
Capacity	650MB	4.7GB	25GB
Laser wavelength	780nm	650nm	405nm
Object lens numerical aperture	0.45	0.6	0.85
Minimum pit size	0.83 $\mu\text{m}$	0.40 $\mu\text{m}$	0.16 $\mu\text{m}$
Track pitch	1.6 $\mu\text{m}$	0.74 $\mu\text{m}$	0.32 $\mu\text{m}$

- [8] As shown in Table 1, with the increasing recording capacity, the pit size and track pitch decrease and technologies to make the pit size and track pitch much smaller are being developed. Here, BD indicates a blue-ray disc.
- [9] Meanwhile, FIG. 1 is a flowchart illustrating a conventional process of manufacturing an information storage medium. The process for manufacturing an information storage medium can be broadly divided into a mastering process and a disc making process. The mastering process is a process for making a stamper from which substrates are injection molded. In the mastering process, a photoresist is coated on a glass substrate in step S10, and exposure is performed by irradiating a laser beam on the photoresist according to a signal corresponding to a mark to be recorded in step S12. Then, by developing the photoresist-coated substrate, a recorded master is made in step S14, and an electrode layer is formed on the glass substrate by Ni sputtering in step S16. Then, metal coating is performed in step S18. On the recorded master, pit shapes and groove shapes are formed.
- [10] Next, the metal coated layer is separated from the recorded master to form a stamper in step S20.
- [11] By using the stamper, a substrate is injection molded in step S22. Then, by sputtering, a recording film is laminated on the injection molded substrate in step S24, and a cover layer is laminated on the recording film in step S26. Through this process, a disc is manufactured in step S28.
- [12] In the manufacturing process, the recording step S12 by irradiating a laser beam can be regarded as one of the most important factors determining a pit size and a track pitch. When the size of pit or a track pitch is desired to be reduced in order to increase a recording capacity, the spot size of a laser beam should be reduced. That is, by reducing the wavelength of a laser beam and increasing the numerical aperture, the spot size of a laser beam can be reduced.

## Disclosure of Invention

### Technical Problem

- [13] However, in discs of a generation after the blue-ray disc (BD), laser has a limitation in achieving high density and high capacity recording. Accordingly, a method using an electronic beam having a short wavelength instead of a laser beam are being newly researched and developed. Thus, new research and development is requested in order to satisfy the high density and high capacity recording requirement.

### Technical Solution

- [14] The present invention provides a recorded master for manufacturing an information storage medium in which the size of a pit and the track pitch size of a groove can be reduced simply without a need to make a shorter wavelength laser beam, a separate layer allowing a metal coated layer for a stamper to be separated from a master is disposed to simplify a manufacturing process, and high density and high capacity recording can be implemented, and a method for manufacturing the master.
- [15] According to an aspect of the present invention, there is provided a recorded master for manufacturing an information storage medium including: a master substrate; a heat absorption layer which is coated on the master substrate and absorbs heat at a part on which a beam is irradiated; and a separation layer which is coated on the heat absorption layer, wherein according to the temperature distribution of the part on which the beam is irradiated, volume change occurs in at least one of the heat absorption layer and the separation layer.
- [16] The separation layer may be formed of a photoresist.
- [17] The heat absorption layer is formed of an alloy layer.
- [18] The alloy layer may be formed of a rare earth element metal and a transition metal.
- [19] The alloy layer may be formed of TbFeCo.
- [20] A dielectric layer may be included on at least one of the top and bottom of the heat absorption layer.
- [21] The heat absorption layer may be formed as an alloy dielectric layer formed of a dielectric and an alloy.
- [22] When the melting point of the heat absorption layer is T1 and the part on which a laser beam is irradiated has a temperature of  $0.5T1$  or over, a volume change may occur in the heat absorption layer and the separation layer part.
- [23] When the melting point of the heat absorption layer is T1, the melting point of the separation layer is T2, and the temperature distribution of the part on which a laser beam is irradiated is equal to or higher than T2 and lower than  $0.5T1$ , volume change

may occur in the separation layer such that a pit is formed.

- [24] When the melting point of the separation layer is T2, the glass transition temperature of the separation layer is T3, and the temperature distribution of the part on which a laser beam is irradiated is equal to or higher than T3 and lower than T2, a volume change may occur in the separation layer such that a bump is formed.
- [25] According to another aspect of the present invention, there is provided a method for fabricating a recorded master for manufacturing an information storage medium including: coating a heat absorption layer which absorbs heat at a part on a master substrate on which a beam is irradiated; coating a separation layer on the heat absorption layer; and by irradiating a laser beam on the heat absorption layer, causing volume change in at least one of the heat absorption layer and the separation layer with respect to the temperature distribution of a part on which the beam is irradiated.

#### **Advantageous Effects**

- [26] According to the recorded master for manufacturing an information storage medium of the present invention, by disposing a heat absorption layer and a separation layer in which the volumes change when the layers are heated up to over a pre-determined temperature, a pit or a bump is formed such that the size of the pit (or bump) or track pitch can be reduced. By doing so, a high density and high capacity information storage medium can be realized without implementing a high numerical aperture of an object lens and a short wavelength of a laser beam.
- [27] Furthermore, separation of a stamper from a master can be easily performed and a stamper with a low surface roughness can be provided by using the recorded master according to the present invention. Also, according to the temperature distribution of a part on which a laser beam is irradiated, a pit or a bump can be selectively formed by volume transformation in a heat absorption layer or in a separation layer. In particular, when a pit or a bump is formed by a volume transformation in the separation layer, the depth of the pit or bump can be restricted to the thickness of the separation layer such that the shape of the pit or bump can be easily controlled.
- [28] In addition, the method for manufacturing a recorded master for manufacturing an information storage medium according to the present invention can be performed by using the conventional mastering equipment without change such that the manufacturing cost is low and by using a laser beam of an identical wavelength, the size of a pit or track pitch can be greatly reduced. Also, the stamper can be easily separated from the heat absorption layer such that the manufacturing process can be simplified.

#### **Description of Drawings**

- [29] The above and other features and advantages of the present invention will become more apparent by describing in detail exemplary embodiments thereof with reference to the attached drawings in which:
- [30] FIG. 1 is a flowchart illustrating a conventional method of manufacturing an information storage medium;
- [31] FIG. 2 is a diagram showing the layer structure of a recorded master for manufacturing an information storage medium according to the present invention;
- [32] FIG. 3 is a diagram showing a state in which a laser beam is irradiated to a recorded master for manufacturing an information storage medium according to the present invention;
- [33] FIG. 4 is a diagram showing a state in which a volume change occurs in a heat absorption layer employed in a recorded master for manufacturing an information storage medium according to the present invention;
- [34] FIG. 5 is a diagram showing a state in which a volume change occurs in a separation layer employed in a recorded master for manufacturing an information storage medium according to the present invention such that a pit is formed;
- [35] FIG. 6 is a diagram showing a state in which a volume change occurs in a separation layer employed in a recorded master for manufacturing an information storage medium according to the present invention such that a bump is formed;
- [36] FIG. 7A is a photo showing an example in which a volume change occurs in a separation layer employed in a recorded master for manufacturing an information storage medium according to the present invention such that a pit is formed;
- [37] FIG. 7B is a photo showing an example in which a volume change occurs in a separation layer employed in a recorded master for manufacturing an information storage medium according to the present invention such that a bump type groove is formed;
- [38] FIG. 8A is a diagram showing a state in which a coated metal layer is formed on a recorded master for manufacturing an information storage medium according to the present invention;
- [39] FIG. 8B is a diagram showing a state in which a coated metal layer is separated from a recorded master for manufacturing an information storage medium according to the present invention; and
- [40] FIG. 9 is a flowchart illustrating a mastering process of a recorded master for manufacturing an information storage medium according to the present invention.

#### Mode for Invention

- [41] The present invention will now be described more fully with reference to the accompanying drawings, in which exemplary embodiments of the invention are shown.
- [42] Referring to FIG. 2, a recorded master 5 for manufacturing an information storage medium according to the present invention includes a heat absorption layer 15 coated on a mater substrate 10, and a separation layer 20 coated on the heat absorption layer 15.
- [43] The heat absorption layer 15 absorbs heat when a beam is irradiated, hereon and a volume change occurs in the part on which the beam is irradiated, or volume change occurs in the separation layer 20. That is, in the heat absorption layer 15, a chemical and physical reaction occurs according to temperature distribution and causes volume change in the heat absorption layer 15 itself or causes volume change only in the separation layer 20.
- [44] The heat absorption layer 15 can be formed as an alloy dielectric layer, which is formed of a dielectric and an alloy, or an alloy layer. Here, the alloy (or the alloy layer) can be formed by including rare earth element metals and transition metals, and the rare earth element metals include Tb and the transition metals may include Fe and Co.
- [45] A dielectric layer can be disposed at least one of the top and bottom of the heat absorption layer 15. FIG. 2 shows a case where a first dielectric layer 11 and a second dielectric layer 12 are disposed on the top and bottom of the heat absorption layer 15, respectively.
- [46] The first and second dielectric layers 11 and 13 can be formed by including a mixture of ZnS and SiO<sub>2</sub>. Preferably, the heat absorption layer is formed of TbFeCo and the first and second dielectric layers 11 and 13 can be formed of ZnS-SiO<sub>2</sub>.
- [47] The separation layer 20 is laminated on the heat absorption layer 15 such that a stamper (Refer to 30 of FIG. 8A) to be explained later can be easily separated from the heat absorption layer 15. The separation layer 20 can be formed of, for example, photoresist. Also, due to the volume change in the heat absorption layer 15, the volume of the separation layer 20 may change together with the heat absorption layer 15, or may change alone.
- [48] Referring to FIG. 3, since a laser beam (L) has a Gaussian distribution, the optical intensity of the central part is relatively stronger than the edge part of the laser beam. Accordingly, if a laser beam is irradiated on the heat absorption layer 15, the temperature of an area on which the central part of the laser beam is irradiated becomes higher than that of an area on which the edge part of the laser beam is irradiated. The laser beam (L) is focused on the heat absorption layer 15 through an

object lens (OL).

- [49] While the recorded master 5 rotates, the laser beam (L) is irradiated on the recorded master 5. At this time, the temperature distribution of an exposed part at the heat absorption layer 15 changes with respect to the linear velocity of the recorded master 5 and the power of the laser beam. According to this temperature distribution, a volume change occurs in at least one of the heat absorption layer 15 and the separation layer 20.
- [50] Assuming that the melting point of the heat absorption layer 15 is T1, the melting point of the separation layer 20 is T2, and the glass transition temperature of the separation layer 20 is T3, if the heat absorption layer 15 is heated up to a temperature in the vicinity of T1, the reaction of the heat absorption layer 15 and dielectric layers causes a volume transformation in the heat absorption layer 15 and according to this, a transformation occurs also in the first and second dielectric layers 11 and 13 and the separation layer 20.
- [51] When a recording condition causing a transformation is simulated, a temperature at which forming of a protrusion part is possible is equal to or over  $0.5T_1$ .
- [52] In other words, a volume change occurs in the part (B) of the heat absorption layer 15 heated up to the vicinity of a predetermined temperature ( $T_1$ ), and a protrusion part 25 as shown in FIG. 4 is formed. This protrusion part 25 becomes a bump or a groove. Hereinafter, a bump will be referred to by reference number 25.
- [53] Next, when the temperature of a part on which a beam is irradiated is substantially lower than  $T_1$ , the reaction between thin films does not occur. Accordingly, as shown in FIG. 5, a volume transformation occurs not in the heat absorption layer 15, but only in the separation layer 20 such that a pit 26 is formed. Here, the temperature of a part on which a beam is irradiated is heated up to a temperature equal to or over  $T_2$  and lower than  $0.5T_1$ , and a pit 26 is formed.
- [54] Meanwhile, if the temperature of a part on which a beam is irradiated is equal to or higher than  $T_3$  and lower than  $T_2$ , as shown in FIG. 6, volume transformation occurs in the separation layer 20 such that a bump 25' is formed. Also at this time, a volume transformation occurs not in the heat absorption layer 15, but occurs only in the separation layer 20. While the pit 26 is formed in FIG. 5, a bump 25' is formed in FIG. 6. When the pit 26 or the bump 25' is formed by the volume transformation in the separation layer 20, the depth of the pit 26 or the height of the bump 25' is limited to the thickness of the separation layer 20. Accordingly, there is an advantage in that the height or depth does not need to be controlled separately.

- [55] As described above, with respect to the temperature of a part on which a beam is irradiated, layers where a volume transformation occurs and the shape of volume transformation change.
- [56] More specifically, a heat absorption layer formed of TbFeCo of a 15nm thickness, a dielectric layer of a 15nm thickness, and a separation layer formed of photoresist of a 50nm thickness are sequentially laminated on a master substrate and information is recorded by irradiating a laser beam. Here, the glass transition temperature of the photoresist is 110-130°C, the melting point of the photoresist is 200-220°C, and the melting point of TbFeCo layer is approximately 1440°C.
- [57] At this time, data was recorded by using a laser beam having a 405nm wavelength, 10MHz pulse, and 13mW recording power, and a recording condition of a 6m/sec linear velocity, and a photo of the result is shown in FIG. 7A. According to the photo, a pit 26 is formed in a separation layer and the depth is 30nm that is the thickness of the photoresist. Also, the size of the pit formed at this time is approximately 150nm. This size cannot be manufactured by the conventional mastering method. Under the conditions described above, it is difficult to measure the temperature of a part on which a laser beam was irradiated, but according to temperature calculation by simulation, the temperature is approximately 400°C.
- [58] Next, when the linear velocity is 6m/sec and the recording power is 10mW, the temperature of an exposed part is approximately 200°C, and in this temperature distribution, a bump (25') type groove is formed as shown in FIG. 7B.
- [59] As shown in FIG. 8A, an electrode layer 27 is laminated on the separation layer 20 and by using this, a metal coated layer 28 is formed. Then, as shown in FIG. 8B, the electrode layer 27 and the metal coated layer 28 are separated from the master 5. Thus, the separated electrode layer 27 and the metal coated layer 28 become a stamper 30.
- [60] At this time, by using a solution capable of melting only the separation layer 20 not affecting the metal coated layer 28, the stamper 30 can be easily separated.
- [61] For example, when the separation layer 20 is formed of a photoresist, separation can be easily performed by melting the photoresist.
- [62] When the stamper 30 is separated from the separation layer 20, the separation layer 20 may not be removed completely and part of the separation layer 20 may remain on the second dielectric layer 13 or on the electrode layer 27. However, even when part of the separation layer 20 remains on either side, the photoresist can be removed easily such that there is no particular difficulty in the manufacturing process. Also, when the separation layer 20 is formed of, for example, a liquid photoresist, the surface of the

separation layer 20 is very smooth and the surface shape of this separation layer 20 is directly transferred to the stamper 30. Accordingly, there is an advantage in that the surface roughness of the stamper 30 is greatly reduced.

[63] Though the pit 26 formed by the volume transformation in the heat absorption layer 15 is shown in FIGS. 8A and 8B, the method for manufacturing a stamper is identical even when the bump 25' is formed.

[64] Thus, the stamper 30 required for injection molding a substrate of an information storage medium is completed. If a substrate is injection molded by using this stamper, the shape of a pit, groove or bump is transferred on the substrate. By sequentially laminating a recording film and a cover layer on this substrate, an information storage medium is manufactured.

[65] Next, referring to FIGS. 2 and 9, in a method for manufacturing a recorded master for manufacturing an information storage medium, the heat absorption layer 15 is coated on the mater substrate 10 in step S20 and the separation layer 20 is coated on the heat absorption layer 15 in step S22.

[66] The heat absorption layer 15 has a characteristic that when the heat absorption layer 15 is heated over a predetermined temperature, a physical and chemical reaction occurs. According to the temperature distribution of a part on which a beam is irradiated, volume transformation occurs in at least one of the heat absorption layer 15 and the separation layer 20 and a pit or a bump is formed.

[67] The temperature of the part on which a beam is irradiated depends on the power of a laser beam or the linear velocity of the master.

[68] As described above, the heat absorption layer is formed of the first dielectric layer 11, the alloy layer 12, and the second dielectric layer 13, or formed as an alloy dielectric layer.

[69] Preferably, the alloy layer 12 is formed of a rare earth element metal and a transition metal, and the rare earth element metal includes Tb and the transition metal includes iron (Fe) and cobalt (Co).

[70] If a laser beam is irradiated on the heat absorption layer 15 in step S24, a part which is heated up over a predetermined temperature in the part on which the laser beam is irradiated swells and a pit (or groove) or a bump is formed. Here, since the laser beam has a Gaussian distribution, the size of the part which is heated up over the predetermined temperature and swells can be minimized. That is, when a laser beam of an identical wavelength and an object lens of an identical numerical aperture are used, a valid spot size of a laser beam can be reduced compared to the conventional man-

factoring method. Here, the valid spot size means a spot size which is practically used to form a pit.

- [71] Though a laser beam is irradiated after the separation layer 20 is coated on the heat absorption layer 15 in the above explanation, a laser beam may be irradiated on the heat absorption layer 15 before laminating the separation layer 20 on the heat absorption layer 15 to form a pit or a groove, and then the separation layer 20 can be coated on the heat absorption layer 15. This method is applied when a volume transformation occurs in the heat absorption layer 15.
- [72] Then, the electrode layer 27 for metal coating is formed on the separation layer 20 in step S26, and by using the electrode layer 27, the metal coated layer 28 is formed in step S28. Then, the bump (or groove) 25 or 25' or the pit 26 formed by volume transformation in at least one of the heat absorption layer 15 and the separation is transferred.
- [73] Next, by removing the separation layer 20, the electrode layer 27 and the metal coated layer 28 are separated from the master 5. When the separation layer 20 is formed by a photoresist, it can be easily removed from the master 5. By doing so, the stamper 30 for injection molding a substrate can be obtained in step S30.
- [74] Depending on whether or not a pit shape remains on the second dielectric layer 13 when the separation layer 20 is removed, it can be confirmed whether volume transformation occurs in the heat absorption layer or the separation layer 20.
- [75] Meanwhile, by varying the thicknesses of the heat absorption layer and the separation layer, the effects of those layers were tested. Here, the first and second dielectric layers 11 and 13 formed of ZnS-SiO<sub>2</sub> and the alloy layer 12 formed of TbFeCo were coated on the glass substrate 10 by sputtering and the separation layer 20 was formed by spin coating positive type photoresist. Then, the thicknesses of the first and second dielectric layers 11 and 13, the alloy layer 12 and the separation layer 20 were transformed as the following table 2:

Table 2

[77]

		Thickness (nm)	Thickness (nm)	Thickness (nm)	Thickness (nm)
		sample 1	sample 2	sample 3	sample 4
1st dielectric layer	ZnS-SiO <sub>2</sub>	170	170	170	170

Alloy layer	TbFeCo	15	15	15	15
2nd dielectric layer	ZnS-SiO <sub>2</sub>	15	15	15	15
Photoresist	Positive type	0	25	50	100

[78] On the substrate prepared as presented in Table 2, a blue laser was irradiated and a pulse of 15MHz was input as a recording signal at a linear velocity of 3 m/sec. After recording by irradiating a laser beam, an electrode layer was spread to the thickness of approximately 100nm, by sputtering, and a stamper was formed by metal coating. After metal coating, whether or not the stamper was separated (separation) was confirmed, and after making the stamper, the depth of a pit was measured. Separation of the stamper was performed mainly between the separation layer and the electrode layer. When a small amount of the separation layer remained on the stamper, it could be easily removed by NaOH aqueous solution.

[79] The test result of the depths of pits formed by varying the thickness of the heat absorption layer and the separation layer as in Table 2 and separation are shown in Table 3:

[80] Table 3

[81]

Sample Number	Pit depth (nm)	Separation
1	65	Not separated
2	60	Separable
3	50	Separable
4	30	Separable

[82] According to the results in Table 3, when there was no separation layer (sample 1), it was impossible to separate the stamper from the heat absorption layer, and accordingly, it can be seen that the stamper cannot be manufactured normally.

[83] Meanwhile, when there was the separation layer, it can be seen that separation of the stamper is possible regardless of the thickness of the separation layer.

[84] Thus by simply coating the separation layer on the heat absorption layer, the stamper for manufacturing an information storage medium can be easily manufactured.

## Claims

- [1] A recorded master for manufacturing an information storage medium comprising:
  - a mater substrate;
  - a heat absorption layer which is coated on the mater substrate and absorbs heat at a part on which a beam is irradiated; and
  - a separation layer which is coated on the heat absorption layer, wherein according to the temperature distribution of the part on which the beam is irradiated, volume change occurs in at least one of the heat absorption layer and the separation layer.
- [2] The recorded master of claim 1, wherein the separation layer is formed of a photoresist.
- [3] The recorded master of claim 1, wherein the heat absorption layer is formed of an alloy layer.
- [4] The recorded master of claim 3, wherein the alloy layer is formed of a rare earth element metal and a transition metal.
- [5] The recorded master of claim 4, wherein the alloy layer is formed of TbFeCo.
- [6] The recorded master of claim 1, wherein a dielectric layer is included on at least one of the top and bottom of the heat absorption layer.
- [7] The recorded master of claim 6, wherein the dielectric layer is formed of a mixture of ZnS and SiO<sub>2</sub>.
- [8] The recorded master of claim 1, wherein the heat absorption layer is formed as an alloy dielectric layer formed of a dielectric and an alloy.
- [9] The recorded master of claim 1, wherein when the melting point of the heat absorption layer is T1 and the part on which a laser beam is irradiated has a temperature of 0.5T1 or over, a volume change occurs in the heat absorption layer and the separation layer part.
- [10] The recorded master of claim 1, wherein when the melting point of the heat absorption layer is T1, the melting point of the separation layer is T2, and the temperature distribution of the part on which a laser beam is irradiated is equal to or higher than T2 and lower than 0.5T1, a volume change occurs in the separation layer and a pit is formed.
- [11] The recorded master of claim 1, wherein when the melting point of the separation layer is T2, the glass transition temperature of the separation layer is

T3, and the temperature distribution of the part on which a laser beam is irradiated is equal to or higher than T3 and lower than T2, volume change occurs in the separation layer and a bump is formed.

- [12] A method of fabricating a recorded master for manufacturing an information storage medium, comprising:
  - coating a heat absorption layer which absorbs heat at a part on a mater substrate on which a beam is irradiated;
  - coating a separation layer on the heat absorption layer; and
  - by irradiating a laser beam on the heat absorption layer to cause a volume change in at least one of the heat absorption layer and the separation layer with respect to the temperature distribution of a part on which the beam is irradiated.
- [13] The method of claim 12, wherein the separation layer is formed of a photoresist.
- [14] The method of claim 12, wherein the heat absorption layer is formed of an alloy layer.
- [15] The method of claim 14, wherein the alloy layer is formed of a rare earth element metal and a transition metal.
- [16] The method of claim 15, wherein the alloy layer is formed of TbFeCo.
- [17] The method of claim 12, wherein a dielectric layer is included on at least one of the top and bottom of the heat absorption layer.
- [18] The method of claim 17, wherein the dielectric layer is formed of a mixture of ZnS and SiO<sub>2</sub>.
- [19] The method of claim 12, wherein the heat absorption layer is formed as an alloy dielectric layer formed of a dielectric and an alloy.
- [20] The method of claim 12, wherein when the melting point of the heat absorption layer is T1 and the part on which a laser beam is irradiated has a temperature of 0.5T1 or over, a volume change occurs in the heat absorption layer and the separation layer part.
- [21] The method of claim 12, wherein when the melting point of the heat absorption layer is T1, the melting point of the separation layer is T2, and the temperature distribution of the part on which a laser beam is irradiated is equal to or higher than T2 and lower than 0.5T1, a volume change occurs in the separation layer and a pit is formed.
- [22] The method of claim 12, wherein when the melting point of the separation layer is T2, the glass transition temperature of the separation layer is T3, and the temperature distribution of the part on which a laser beam is irradiated is equal to

or higher than T3 and lower than T2, a volume change occurs in the separation layer and a bump is formed.

- [23] The method of claim 12, wherein the temperature of a part on which a beam is irradiated depends on the power of the beam and the linear velocity of the master.

## Abstract

A recorded master for manufacturing an information storage medium and a method of manufacturing the master are provided. The recorded master includes: a master substrate; a heat absorption layer which is coated on the master substrate and absorbs heat at a part on which a beam is irradiated; and a separation layer which is coated on the heat absorption layer, wherein according to the temperature distribution of the part on which the beam is irradiated, a volume change occurs in at least one of the heat absorption layer and the separation layer. With this structure, a stamper can be easily separated from a transform layer, a recorded master with a low surface roughness can be provided, and a high density information storage medium can be manufactured.

FIG. 1

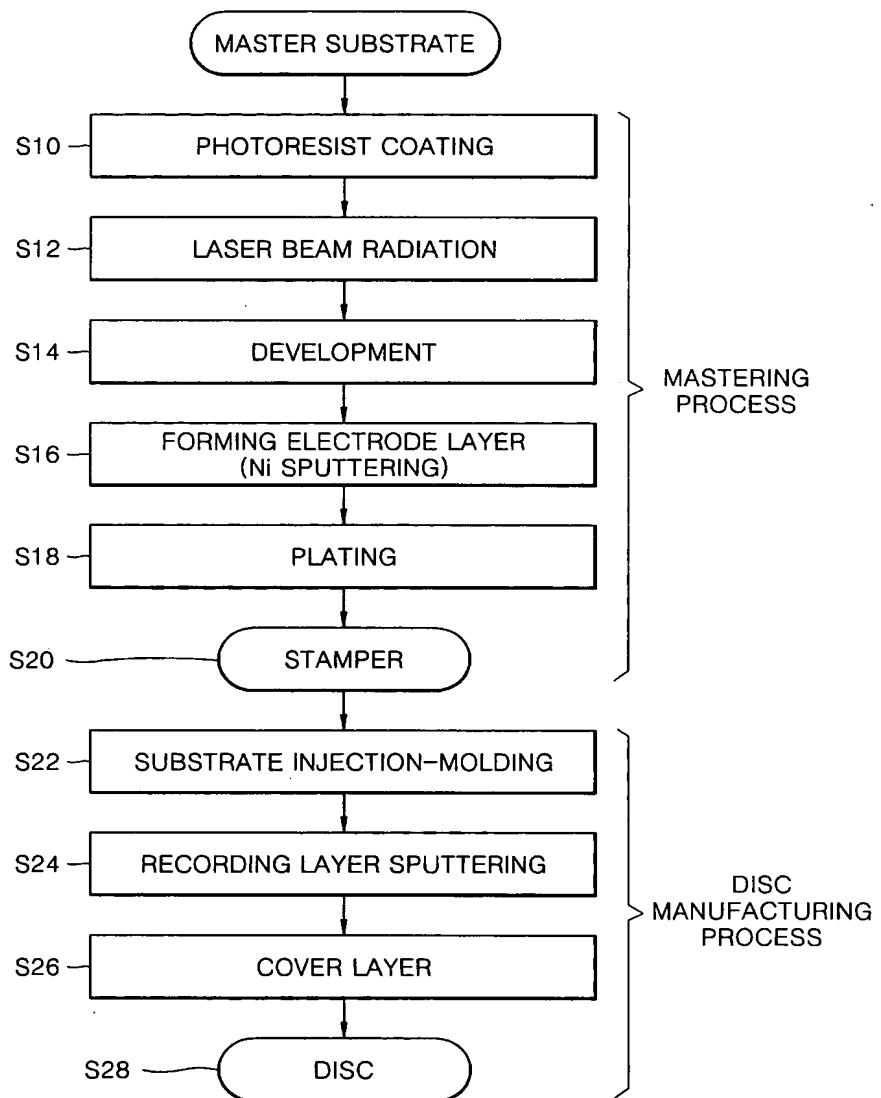


FIG. 2

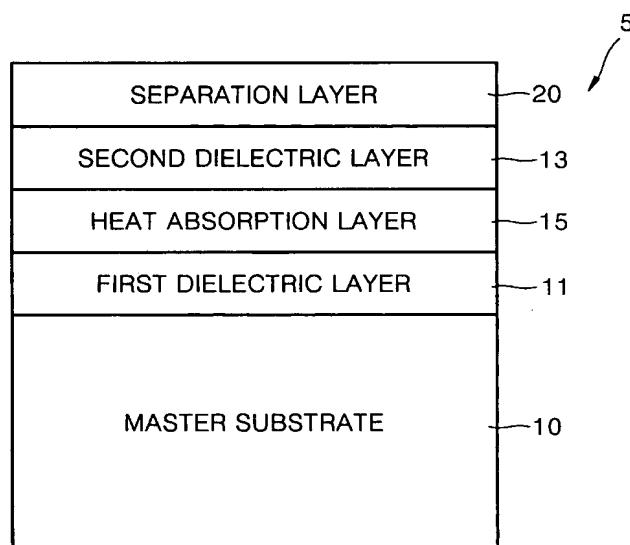


FIG. 3

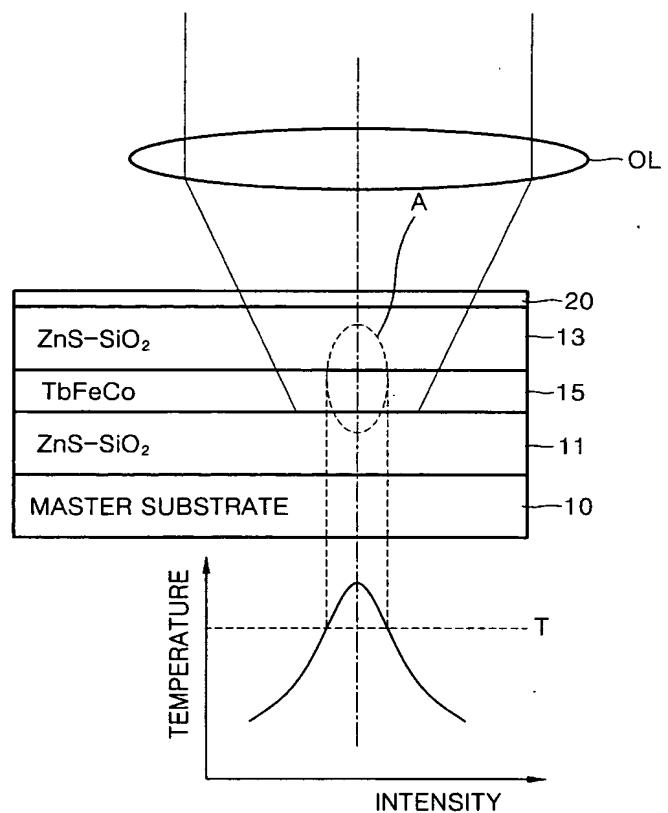


FIG. 4

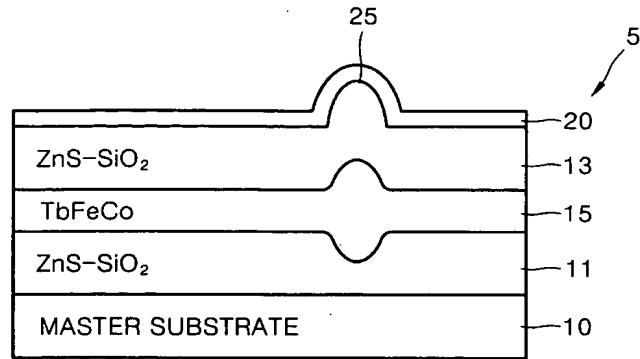


FIG. 5

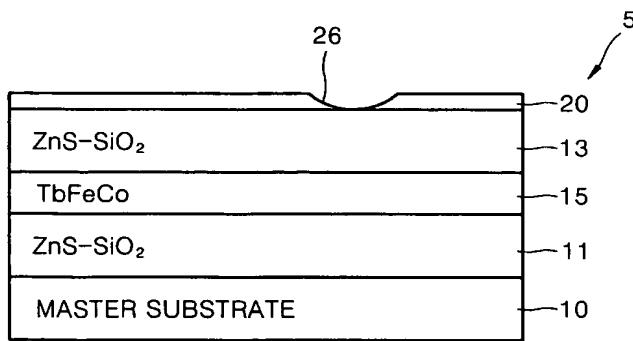


FIG. 6

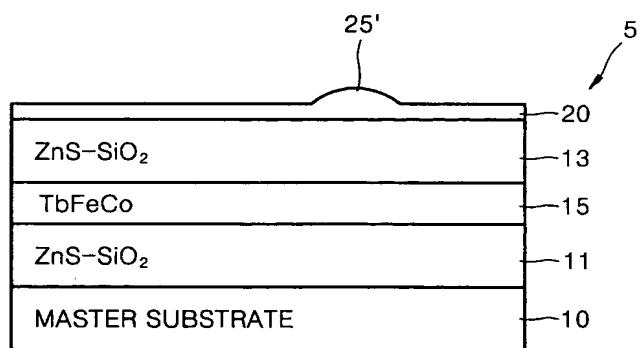


FIG. 7A

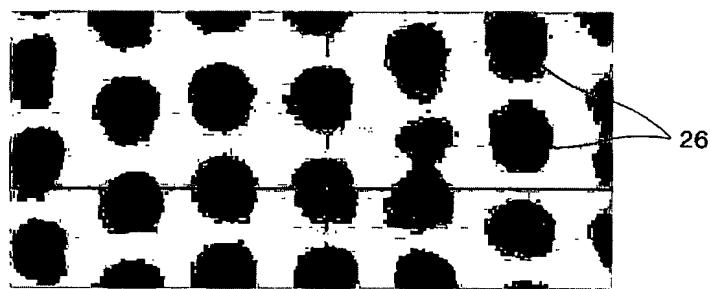


FIG. 7B



FIG. 8A

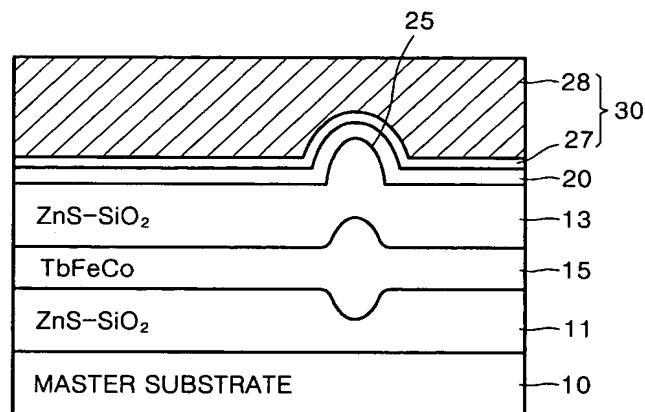


FIG. 8B

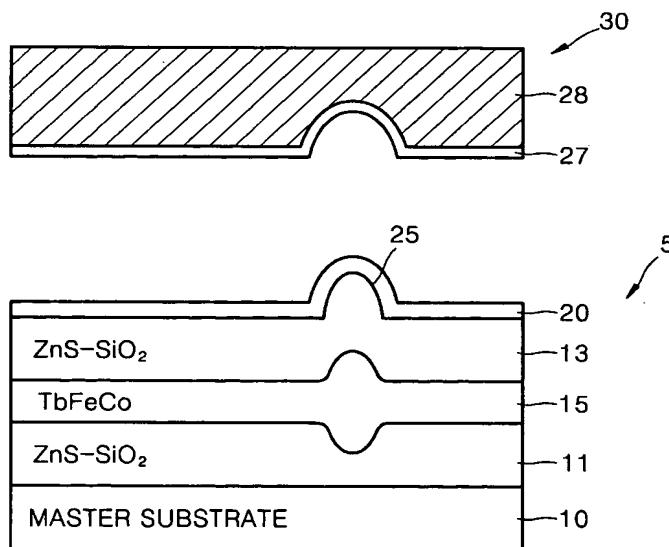
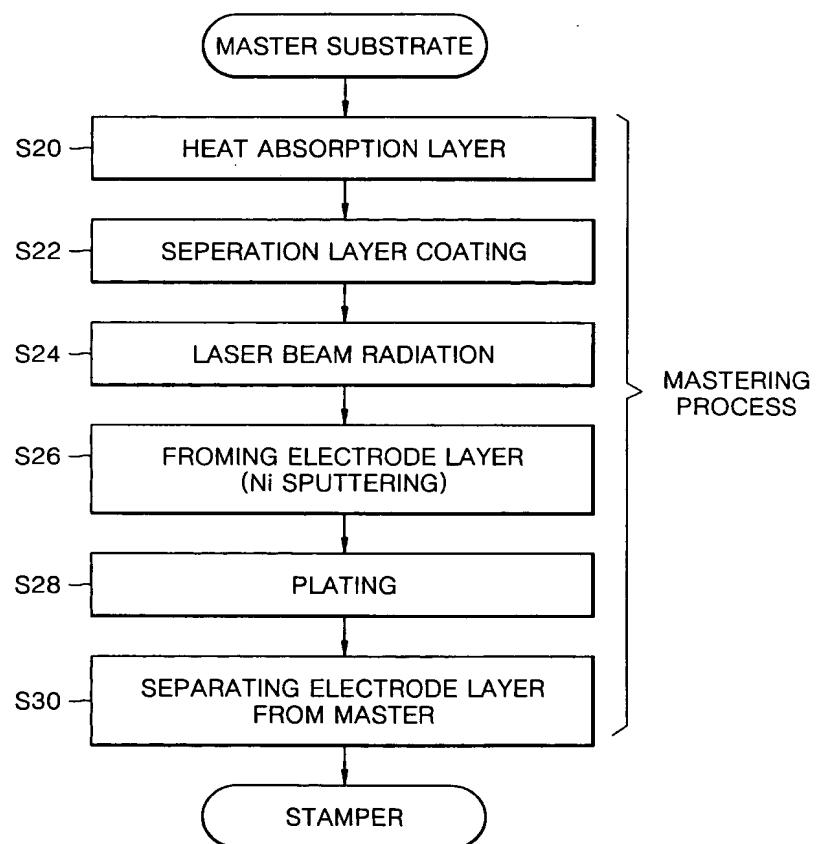


FIG. 9



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